## SQJ147ELP

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**Vishay Siliconix** 

## Automotive P-Channel 40 V (D-S) 175 °C MOSFET

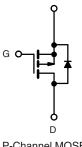


PRODUCT SUMMARY	
V <sub>DS</sub> (V)	-40
$R_{DS(on)} (\Omega)$ at $V_{GS} = -10 V$	0.0125
$R_{DS(on)} (\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.018
I <sub>D</sub> (A)	-90
Configuration	Single
Package	PowerPAK SO-8L

#### **FEATURES**

- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 qualified
- 100 % R<sub>q</sub> and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>





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P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ( $T_{\rm C}$ =	= 25 °C, unles	s otherwise noted	)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V <sub>DS</sub>	-40	v
Gate-source voltage <sup>a</sup>		V <sub>GS</sub>	± 20	v
Continuous drain current	$T_C = 25 \ ^\circ C \ ^b$	I-	-90	
	T <sub>C</sub> = 125 °C	I <sub>D</sub>	-52	
Continuous source current (diode conduction) <sup>b</sup>		I <sub>S</sub>	-90	А
Pulsed drain current <sup>c</sup>		I <sub>DM</sub>	-200	
Single pulse avalanche current L = 0.1 mH		I <sub>AS</sub>	-41	
Single pulse avalanche energy	L = 0.1 mm	E <sub>AS</sub>	45	mJ
Maximum accuration fination C	T <sub>C</sub> = 25 °C	PD	183	w
Maximum power dissipation <sup>c</sup>	T <sub>C</sub> = 125 °C	гD	61	vv
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C
Soldering recommendations (peak temperature) d, e			260	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount <sup>f</sup>	R <sub>thJA</sub>	46	°C/W	
Junction-to-case (drain)		R <sub>thJC</sub>	0.82	0/10	

#### Notes

- a. Not intended for continuous use with positive gate voltage > 5.0 V
- b. Package limited
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (<u>www.vishay.com/doc?73257</u>). For PowerPAK SO-8L, the end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

f. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%$ 

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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static								
Drain-source breakdown voltage	V <sub>DS</sub>	V <sub>GS</sub>	$V_{GS} = 0, I_D = -250 \ \mu A$		-	-	v	
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	V <sub>GS</sub> , I <sub>D</sub> = -250 μA	-1.5	-2.0	-2.5	v	
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, $V_{GS} = \pm 20 V$	-	-	± 100	nA	
		$V_{GS} = 0 V$	V <sub>DS</sub> = -40 V	-	-	-1	μA	
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = -40 V, T <sub>J</sub> = 125 °C	-	-	-50		
		$V_{GS} = 0 V$	V <sub>DS</sub> = -40 V, T <sub>J</sub> = 175 °C	C1:	-150	7		
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = -10 V	$V_{DS} \ge -5 V$	-30	-	-	Α	
		V <sub>GS</sub> = -10 V	I <sub>D</sub> = -10 A	-	0.01	0.0125		
Durain acturas an atata registernas à	Р	V <sub>GS</sub> = -10 V	I <sub>D</sub> = -10 A, T <sub>J</sub> = 125 °C	-	-	0.019		
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10 V	l <sub>D</sub> = -10 A, T <sub>J</sub> = 175 °C	-	-	0.023	52	
		$V_{GS} = -4.5 V$	I <sub>D</sub> = -8 A	-	0.0144	0.018	V nA μA A Ω S S PF nC Ω nS nS	1
Forward transconductance b	9 <sub>fs</sub>	V <sub>DS</sub> =	-	45	-	S		
Dynamic <sup>b</sup>								
Input capacitance	C <sub>iss</sub>		V <sub>DS</sub> = -25 V, f = 1 MHz	-	4225	5500	pF	
Output capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$		-	305	400		
Reverse transfer capacitance	C <sub>rss</sub>			-	281	365		
Total gate charge <sup>c</sup>	Qg			-	85	120		
Gate-source charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = -10 V	$V_{DS} = -20 \text{ V}, \text{ I}_{D} = -10 \text{ A}$	-	14.5	-	nC	
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>			-	14.8	-		
Gate resistance	R <sub>g</sub>	f = 1 MHz		1.7	3.9	6.2	Ω	
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>				12	18	ns	
Rise time <sup>c</sup>	t <sub>r</sub>	$V_{DD}$ = -20 V, R <sub>L</sub> = 2 $\Omega$ , I <sub>D</sub> $\cong$ -10 A, V <sub>GEN</sub> = -10 V, R <sub>g</sub> = 1 $\Omega$		-	4	6		
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>			-	66	99		
Fall time <sup>c</sup>	t <sub>f</sub>			-	16	24		
Source-Drain Diode Ratings and Charac	cteristics <sup>b</sup>							
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	-200	А	
Forward voltage	V <sub>SD</sub>	I <sub>F</sub> = -10 A, V <sub>GS</sub> = 0 V		-	-0.76	-1.2	V	
Body diode reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = -10 A, di/dt = 100 A/μs		-	20	40	ns	
Body diode reverse recovery charge	Q <sub>rr</sub>			-	14	28	nC	
Reverse recovery fall time	ta			-	11	-		
Reverse recovery rise time	t <sub>b</sub>	7		-	8	-	ns	
Body diode peak reverse recovery		1			1		1	

Notes

a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%$ 

b. Guaranteed by design, not subject to production testing

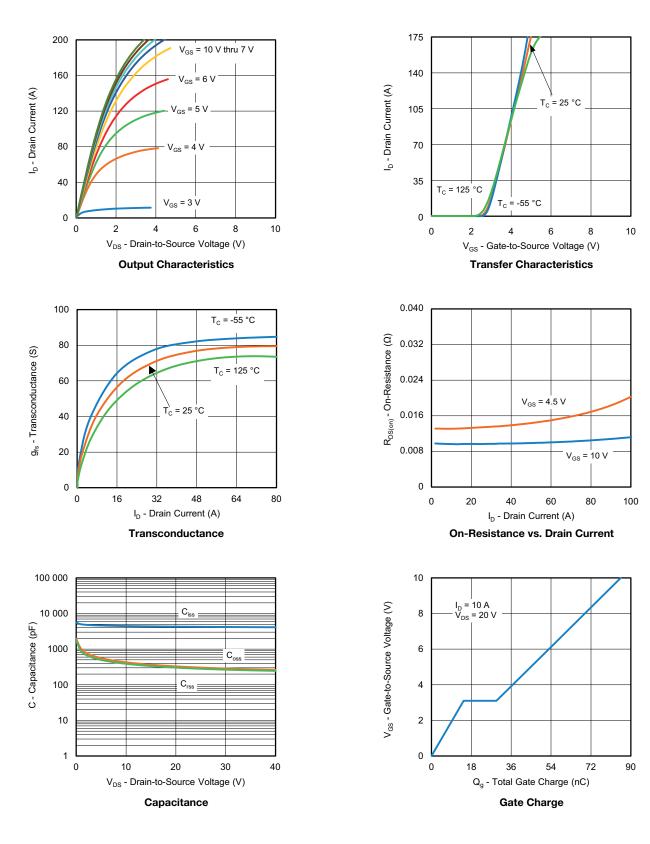
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



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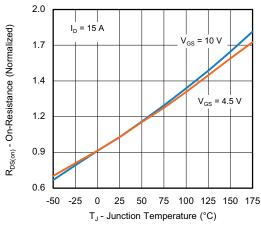
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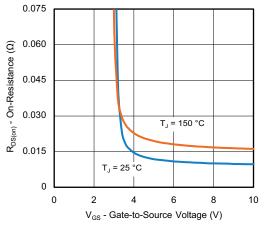
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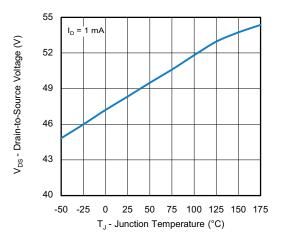
### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



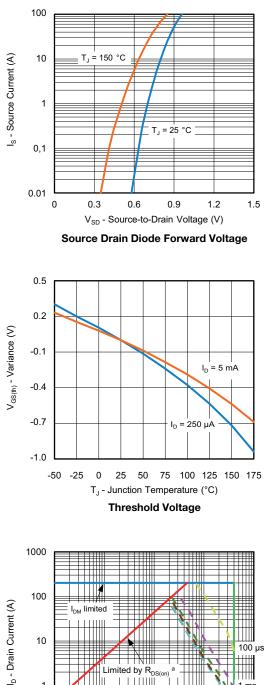
**On-Resistance vs. Junction Temperature** 

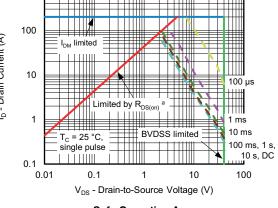


**On-Resistance vs. Gate-to-Source Voltage** 

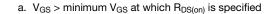


**Drain-Source Breakdown vs. Junction Temperature** 





#### Safe Operating Area



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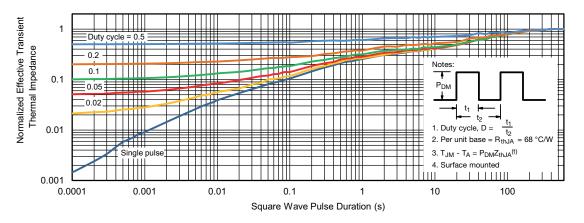
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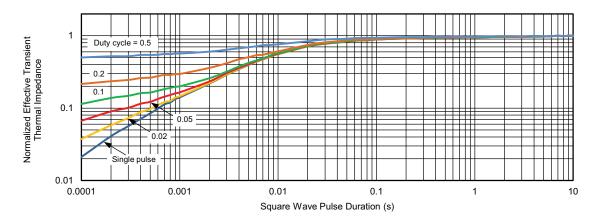
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### THERMAL RATINGS (T<sub>C</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

#### Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

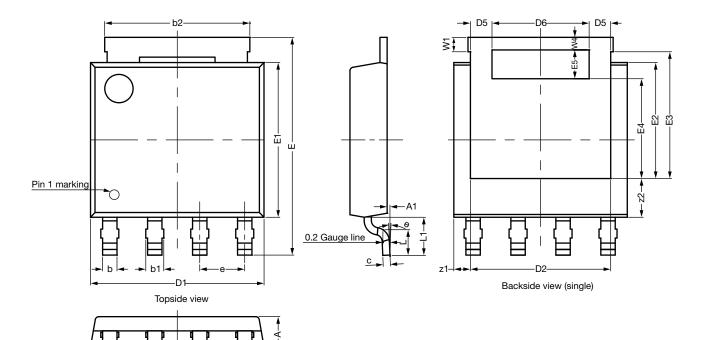
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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# PowerPAK<sup>®</sup> SO-8L (PPKSO8LWLA) Case Outline 3



DIM.		MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX		
А	1.00	1.05	1.10	0.039	0.041	0.043		
A1	0.00		0.127	0.000		0.005		
b	0.33	0.41	0.49	0.013	0.016	0.019		
b1	0.43	0.51	0.59	0.017	0.020	0.023		
b2	4.00	4.10	4.20	0.157	0.161	0.165		
С	0.15	0.20	0.25	0.006	0.008	0.010		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.86	3.96	4.06	0.152	0.156	0.160		
D5	0.51	0.61	0.71	0.020	0.024	0.028		
D6	2.64	2.74	2.84	0.104	0.108	0.112		
е		1.27 BSC		0.050 BSC				
E	6.05	6.15	6.25	0.238	0.242	0.246		
E1	4.27	4.37	4.47	0.168	0.172	0.176		
E2	3.18	3.28	3.38	0.125	0.129	0.133		
E3	3.48	3.58	3.68	0.137	0.141	0.145		
E4	2.72	2.82	2.92	0.107	0.111	0.115		
E5	0.71	0.81	0.91	0.028	0.032	0.036		
L	0.62	0.72	0.82	0.024	0.028	0.032		
L1	0.92	1.07	1.22	0.036	0.042	0.048		
W1	0.31	0.41	0.51	0.012	0.016	0.020		
W4	0.31	0.36	0.41	0.012	0.014	0.016		
z1	0.37	0.47	0.57	0.015	0.019	0.022		
z2	0.99	1.09	1.19	0.039	0.043	0.047		
θ	0°		5°	0°		5°		

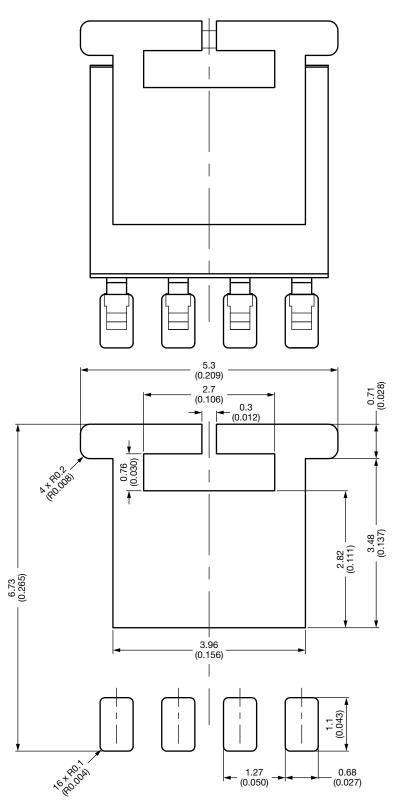
Note

• Millimeter will govern

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# **Recommended Land Pattern PowerPAK® SO-8L Single Short Ear**



Dimensions in Millimeters (Inches)

Revision: 24-Aug-2021

Document Number: 78020



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